

(19)



JAPANESE PATENT OFFICE

PATENT ABSTRACTS OF JAPAN

(11) Publication number: 11126690 A

(43) Date of publication of application: 11 . 05 . 99

(51) Int. Cl

H05B 33/10
H05B 33/02
H05B 33/14

(21) Application number: 10098818

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(22) Date of filing: 10 . 04 . 98

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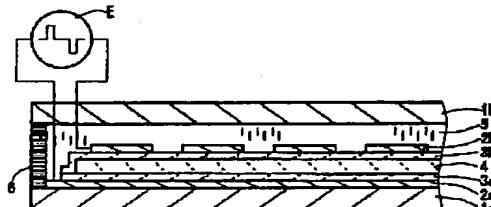
(30) Priority: 20 . 08 . 97 JP 09223623

(54) MANUFACTURE OF THIN FILM
ELECTROLUMINESCENT ELEMENT

(57) Abstract:

PROBLEM TO BE SOLVED: To provide the manufacturing method of an EL element using an alkali earth metal sulfide as a luminescent layer, with high luminescent brightness and high life characteristics in spite of using a non-alkali glass substrate.

SOLUTION: In the manufacturing method of a thin EL element formed by laminating a first electrode 2a, a first insulating layer 3a, a luminescent layer 4, a second insulating layer 3b, and a second electrode 2b on a non-alkali glass substrate 1a in order, at least after the luminescent layer 4 is formed, the non-alkali glass substrate 1a is held at a temperature which is a deformation limit temperature or lower in a single heat treatment method and a first holding temperature near to the deformation limit temperature, then heat treated at a second holding temperature higher than the first holding temperature.



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